NSN 5961-01-123-6576

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-123-6576 **Inclosure Material:** Ceramic **Overall Length:** 0.300 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 140.0 collector to base voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No